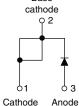


Ultrafast Rectifier, 8 A FRED Pt®





TO-220AC

Base

FEATURES

- · Ultrafast and soft recovery time
- · Optimized forward voltage drop
- Polyimide passivation
- 175 °C maximum operating junction temperature
- Rugged design
- · Good thermal performance
- Meets JESD 201 class 2 whisker test

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





RoHS HALOGEN

FREE

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized forward voltage drop, ultrafast recovery time, and soft recovery. Polyimide passivated with a planar structure and platinum doped life time control guarantee ruggedness, reliability, and offer a solid value for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery chargers, inverters for solar inverters or as freewheeling diodes in motor drives.

PRODUCT SUMMARY					
I _{F(AV)}	8 A				
V _R	1200 V				
V _F at I _F at 125 °C	1.95 V				
t _{rr} typ.	42 ns				
T _J max.	175 °C				
Package	TO-220AC				
Diode variation	Single die				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	$T_C = 140 ^{\circ}\text{C}, D = 0.50$	8				
Non-repetitive peak surge current	I _{FSM}	T_C = 25 °C, t_p = 10 ms, sine wave	80	А			
Repetitive peak forward current	I _{FRM}		16				
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 200 μΑ	1200	-	-			
Forward voltage	V	I _F = 8 A	-	2.05	2.55	2.55 V		
	V _F	I _F = 8 A, T _J = 125 °C	-	1.95	2.37			
Deverage leakage assurent		V _R = V _R rated	-	-	55			
Reverse leakage current	I _R	T _J = 125 °C, V _R = V _R rated	-	-	100	μA		
Junction capacitance	C _T	V _R = 200 V	-	8	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 1.0 \text{ A}$	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{A}, V_R = 30 \text{ V}$		42	-		
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 8 A dI _F /dt = 100 A/μs V _R = 390 V	-	144	-	ns	
		T _J = 125 °C		-	204	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	5	-	Α	
		T _J = 125 °C		-	7.2	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	370	-	200	
		T _J = 125 °C		-	745	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R _{thJC}		-	1.25	1.5			
Thermal resistance, junction to case	R _{thJA}	Typical socket mount	-	54	60	°C/W		
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.18	0.4			
Weight			-	0.2	-	g		
vveignt			-	0.07	-	oz.		
Mounting torque			6.0	_	12	kgf · cm		
			(5.0)		(10)	(lbf · in)		
Marking device		Case style TO-220AC	8ETU12					

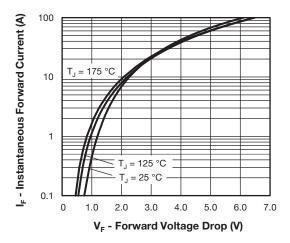


Fig. 1 - Typical Forward Voltage Drop Characteristics

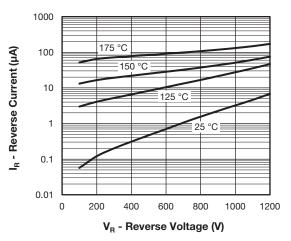


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



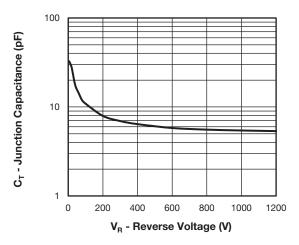


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

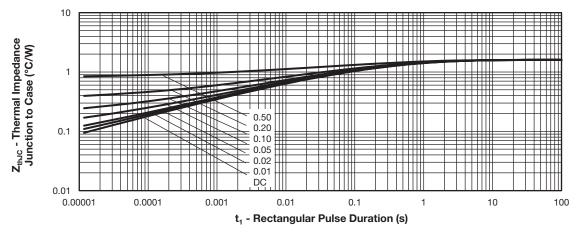


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

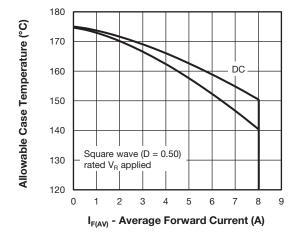


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

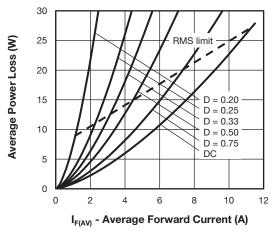


Fig. 6 - Forward Power Loss Characteristics

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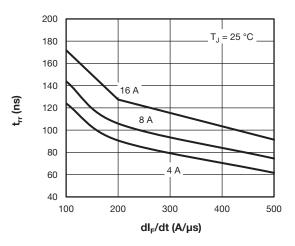


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

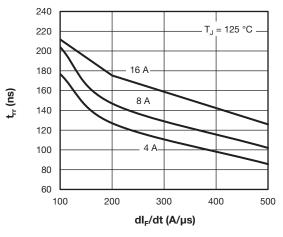


Fig. 8 - Typical Reverse Recovery Time vs. dI_F/dt

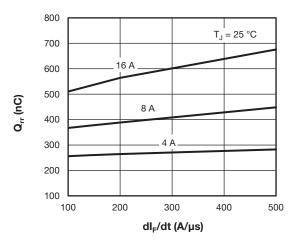


Fig. 9 - Typical Stored Charge vs. dI_F/dt

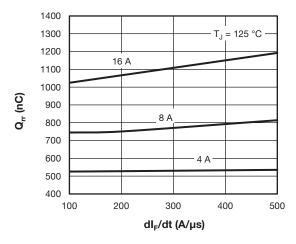


Fig. 10 - Typical Stored Charge vs. dl_F/dt

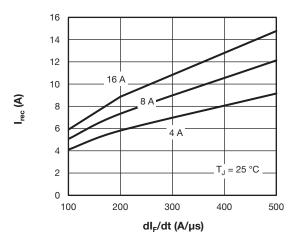


Fig. 11 - Typical Reverse Current vs. dl_F/dt

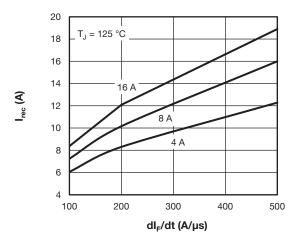
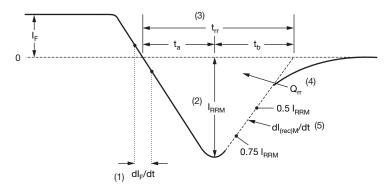


Fig. 12 - Typical Reverse Current vs. dl_F/dt



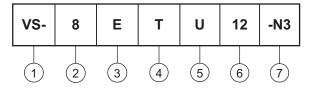


- (1) dl_F/dt rate of change of current through zero crossing
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (5) $dI_{(rec)M}/dt$ peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating (8 = 8 A)
- 3 E = single diode
- 4 Package:

T = TO-220

5 - U = ultrafast recovery

6 - Voltage rating (12 = 1200 V)

7 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

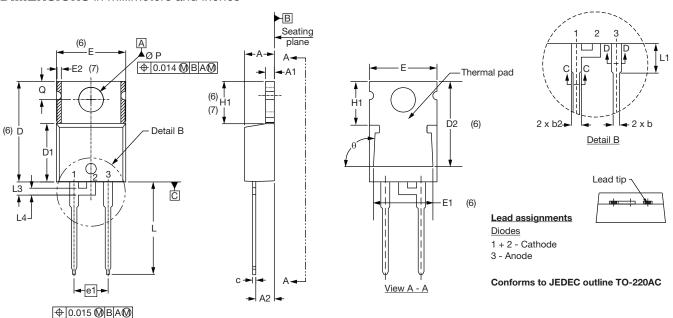
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8ETU12-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95221					
Part marking information	www.vishay.com/doc?95068					



TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

CAMBOI	SYMBOL MILLIMETERS INCHI		HES	NOTES	
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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